



PDA-A13A3-5G

5GHz 1310nm/1550nm Analog InGaAs PIN Photodiode in TO-46 Package, 3-pin

Overview

The Lasermate PDA-A13A3-5G is an Analog InGaAs photodiode designed for analog optical links with bandwidth up to 5GHz.



Features

- InGaAs PIN PD 3 pin TO for Analog application
- Industry standard TO-46 package with 1550nm AR coating cap lens and tab-less
- High responsivity at long wavelength
- Design for fiber optic application
- Low inter-modulation distortion

Applications

- Optimized for fiber optic application
- Suitable for CATV application

Specifications

Electro-Optical Characteristics (Typical values are at 25°C)						
Parameters	Symbol	Min.	Typ.	Max.	Unit	Conditions
Responsivity	R	0.8	0.9		A/W	$\lambda=1310\text{nm}$, $V_R=5\text{V}$
		0.9	1			$\lambda=1550\text{nm}$, $V_R=5\text{V}$
Dark Current	I_D		0.1	1	nA	$V_R=5\text{V}$, $T_A=25^\circ\text{C}$
Breakdown Voltage	V_{BD}	25	40		V	$I_R=10\mu\text{A}$
Second Order Inter-Modulation Distortion	IMD2		-75	-65	dBc	$\lambda=1550\text{nm}$ ⁽¹⁾
Capacitance	C		0.4	0.55	pF	$V_R=5\text{V}$, $f=1\text{MHz}$
Bandwidth	BW	5	6.5			$V_R=5\text{V}$

(1) IMD2 measured at $V_R = 12\text{V}$, $P_{\text{avg}} = 0\text{dBm}$, $\text{OMI} = 0.7$, $R_{\text{load}} = 50\Omega$, $f_1+f_2 = 850\text{MHz}$, $f_1-f_2 = 50\text{MHz}$. All are measured at 25°C.

Absolute Maximum Ratings				
Parameters	Min.	Max.	Unit	Conditions
Storage Temperature	-40	125	°C	
Operating Temperature	-40	85	°C	
Lead Solder Temperature		260	°C	10 seconds
Forward Current		10	mA	
Reverse Voltage		20	V	

Typical Characteristics

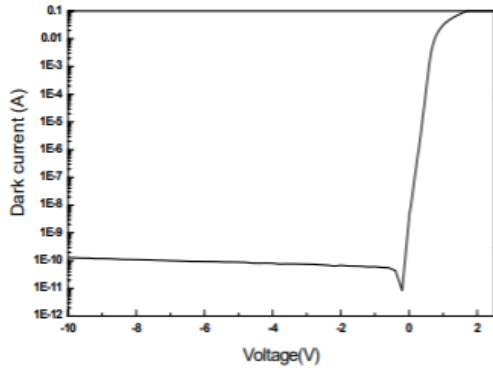


Fig. 1 Typical Dark Current and Forward Current.

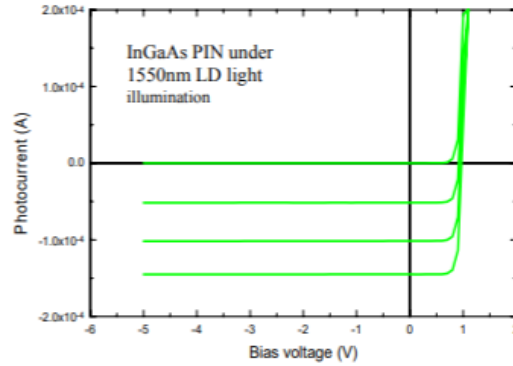


Fig. 2 Typical Photo-Current

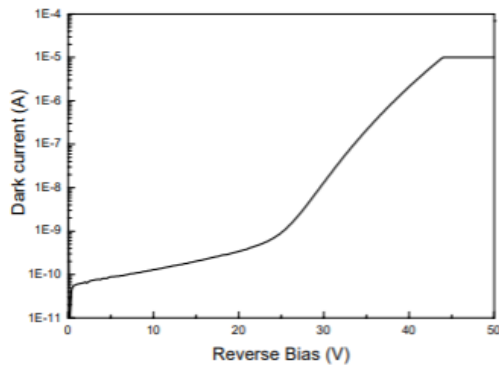


Fig. 3 Typical Breakdown Curve.

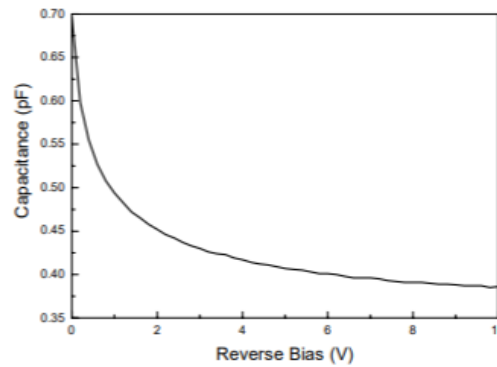
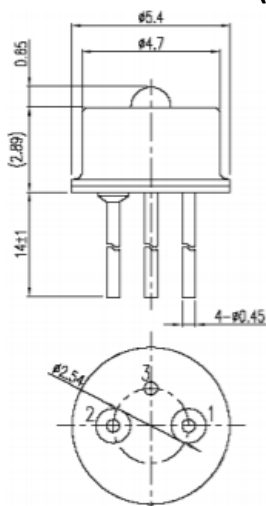


Fig. 4 Typical C-V Curve

Outline Dimensions (unit: mm)



- Pinout:**
1. Anode
 2. Cathode
 3. Case

Note: Specifications are subject to change without notice.